

# 2N404A Transistors

## Ge PNP Lo-Pwr BJT

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Military/High-Rel N

V(BR)CEO (V) 35

V(BR)CBO (V) 40

I(C) Max. (A) 150m

Absolute Max. Power Diss. (W) 150m

Maximum Operating Temp (°C) 100

I(CBO) Max. (A) 5.0u

@V(CBO) (V) (Test Condition) 12

h(FE) Min. Current gain.

h(FE) Max. Current gain.

@I(C) (A) (Test Condition)

@V(CE) (V) (Test Condition)

h(fe) Min. SS Current gain.

@I(C) (A) (Test Condition)

@V(CE) (V) (Test Condition)

@Freq. (Hz) (Test Condition)

f(T) Min. (Hz) Transition Freq 4.0M:

@I(C) (A) (Test Condition) 1.0m

@V(CE) (V) (Test Condition) 6.0

C(obo) (Max) (F) 20p

@V(CB) (V) (Test Condition) 6.0

PDF.Support